





#### EMK13 H 2 H -4.915M

±50ppm Maximum over -40°C to +85°C

Nominal Frequency
4.915MHz

Output Control Function

+85°C

Duty Cycle
50 ±5(%)

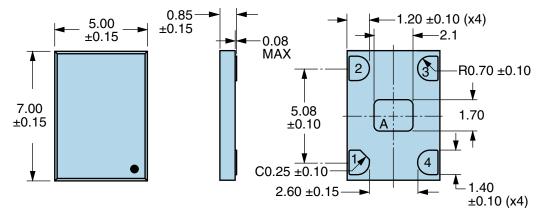
Tri-State (Disabled Output: High Impedance)

| ELECTRICAL SPECIFICATIONS       |  |  |
|---------------------------------|--|--|
| Nominal Frequency               | 4.915MHz   |  |
| Frequency Tolerance/Stability   | ±50ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration) |  |
| Aging at 25°C                   | ±1ppm Maximum First Year   |  |
| Operating Temperature Range     | -40°C to +85°C   |  |
| Supply Voltage                  | 3.3Vdc ±10%  |  |
| Input Current                   | 20mA Maximum   |  |
| Output Voltage Logic High (Voh) | 90% of Vdd Minimum (IOH=-8mA)  |  |
| Output Voltage Logic Low (Vol)  | 10% of Vdd Maximum (IOL=+8mA)  |  |
| Rise/Fall Time                  | 2nSec Maximum (Measured from 20% to 80% of waveform)   |  |
| Duty Cycle                      | 50 ±5(%) (Measured at 50% of waveform)   |  |
| Load Drive Capability           | 15pF Maximum   |  |
| Output Logic Type               | CMOS   |  |
| Output Control Function         | Tri-State (Disabled Output: High Impedance)  |  |
| Output Control Input Voltage    | +0.7Vdd Minimum or No Connect to Enable Output, +0.3Vdd Maximum to Disable Output  |  |
| Peak to Peak Jitter (tPK)       | 500pSec Maximum, 200pSec Typical   |  |
| Start Up Time                   | 50mSec Maximum   |  |
| Storage Temperature Range       | -55°C to +125°C  |  |

| ENVIRONMENTAL & MECHANICAL SPECIFICATIONS |  |  |
|---|--|--|
| ESD Susceptibility                        | MIL-STD-883, Method 3015, Class 2, HBM 2000V                       |  |
| Flammability                              | UL94-V0  |  |
| Mechanical Shock                          | MIL-STD-883, Method 2002, Condition G, 30,000G                     |  |
| Moisture Resistance                       | MIL-STD-883, Method 1004   |  |
| Moisture Sensitivity Level                | J-STD-020, MSL 1   |  |
| Resistance to Soldering Heat              | MIL-STD-202, Method 210, Condition K                               |  |
| Resistance to Solvents                    | MIL-STD-202, Method 215  |  |
| Solderability                             | MIL-STD-883, Method 2003 (Four I/O Pads on bottom of package only) |  |
| Temperature Cycling                       | MIL-STD-883, Method 1010, Condition B                              |  |
| Thermal Shock                             | MIL-STD-883, Method 1011, Condition B                              |  |
| Vibration                                 | MIL-STD-883, Method 2007, Condition A, 20G                         |  |



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**



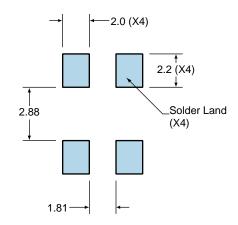
Note A: Center paddle is connected internally to oscillator ground (Pad 2).

| PIN | CONNECTION                 |
|-----|----------------------------|
| 1   | Tri-State (High Impedance) |
| 1   | Power Down (Logic Low)     |
| 2   | Ground                     |
| 3   | Output                     |
| 4   | Supply Voltage             |

| LINE | MARKING   |
|------|---|
| 1    | XXXX or XXXXX<br>XXXX or XXXXX=Ecliptek<br>Manufacturing Lot Code |

#### **Suggested Solder Pad Layout**

All Dimensions in Millimeters



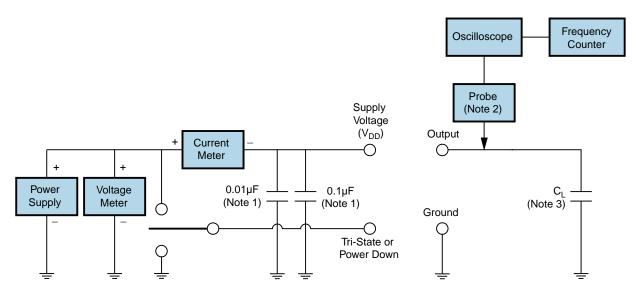
All Tolerances are ±0.1



#### **OUTPUT WAVEFORM & TIMING DIAGRAM**



#### **Test Circuit for CMOS Output**



- Note 1: An external  $0.1\mu\text{F}$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu\text{F}$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



## **Recommended Solder Reflow Methods**



### **High Temperature Infrared/Convection**

| T <sub>s</sub> MAX to T <sub>∟</sub> (Ramp-up Rate) | 3°C/second Maximum                   |
|---|--------------------------------------|
| Preheat   |                                      |
| - Temperature Minimum (T <sub>s</sub> MIN)          | 150°C                                |
| - Temperature Typical (T <sub>s</sub> TYP)          | 175°C                                |
| - Temperature Maximum (T <sub>S</sub> MAX)          | 200°C                                |
| - Time (t <sub>s</sub> MIN)                         | 60 - 180 Seconds                     |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )    | 3°C/second Maximum                   |
| Time Maintained Above:                              |                                      |
| - Temperature (T∟)                                  | 217°C                                |
| - Time (t∟)   | 60 - 150 Seconds                     |
| Peak Temperature (T <sub>P</sub> )                  | 260°C Maximum for 10 Seconds Maximum |
| Target Peak Temperature (T <sub>P</sub> Target)     | 250°C +0/-5°C                        |
| Time within 5°C of actual peak (tp)                 | 20 - 40 seconds                      |
| Ramp-down Rate                                      | 6°C/second Maximum                   |
| Time 25°C to Peak Temperature (t)                   | 8 minutes Maximum                    |
| Moisture Sensitivity Level                          | Level 1                              |
|   |                                      |



### **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

| T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate) | 5°C/second Maximum                                     |
|---|--|
| Preheat   |  |
| - Temperature Minimum (T <sub>s</sub> MIN)          | N/A  |
| - Temperature Typical (T <sub>S</sub> TYP)          | 150°C  |
| - Temperature Maximum (T <sub>s</sub> MAX)          | N/A  |
| - Time (t <sub>s</sub> MIN)                         | 60 - 120 Seconds                                       |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )    | 5°C/second Maximum                                     |
| Time Maintained Above:                              |  |
| - Temperature (T∟)                                  | 150°C  |
| - Time (t∟)   | 200 Seconds Maximum                                    |
| Peak Temperature (T <sub>P</sub> )                  | 240°C Maximum  |
| Target Peak Temperature (T <sub>P</sub> Target)     | 240°C Maximum 1 Time / 230°C Maximum 2 Times           |
| Time within 5°C of actual peak (tp)                 | 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time |
| Ramp-down Rate                                      | 5°C/second Maximum                                     |
| Time 25°C to Peak Temperature (t)                   | N/A  |
| Moisture Sensitivity Level                          | Level 1  |

### Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

#### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.